TOSHIBA Transistor Silicon NPN Triple Diffused Type

# 2SC5200

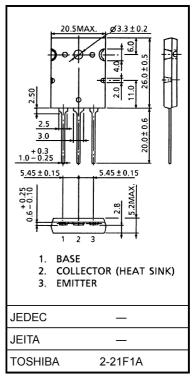
### **Power Amplifier Applications**

Unit: mm

- High breakdown voltage:  $V_{CEO} = 230 \text{ V (min)}$
- Complementary to 2SA1943
- Suitable for use in 100-W high fidelity audio amplifier's output stage

## **Maximum Ratings (Tc = 25°C)**

Characteristics	Symbol	Rating	Unit
Collector-base voltage	V <sub>CBO</sub>	230	V
Collector-emitter voltage	V <sub>CEO</sub>	230	V
Emitter-base voltage	V <sub>EBO</sub>	5	V
Collector current	Ic	15	Α
Base current	I <sub>B</sub>	1.5	Α
Collector power dissipation (Tc = 25°C)	P <sub>C</sub>	150	W
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	−55 to 150	°C



#### Weight: 9.75 g (typ.)

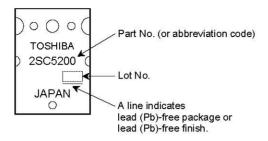
# **Electrical Characteristics (Tc = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 230 V, I <sub>E</sub> = 0	_	_	5.0	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0	_	_	5.0	μA
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = 50 mA, I <sub>B</sub> = 0	230	_	_	٧
DC current gain	h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	55	_	160	
	h <sub>FE (2)</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 7 A	35	60	_	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 8 A, I <sub>B</sub> = 0.8 A	_	0.4	3.0	٧
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 7 A	_	1.0	1.5	٧
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 1 A	_	30	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	200	_	pF

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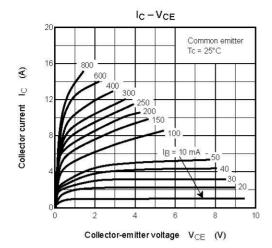
Note: hFE (1) classification R: 55 to 110, O: 80 to 160

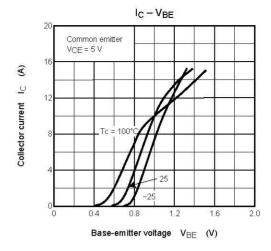
# Marking

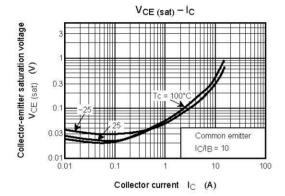


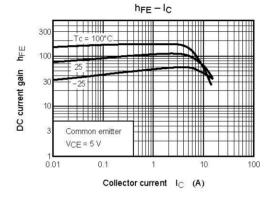
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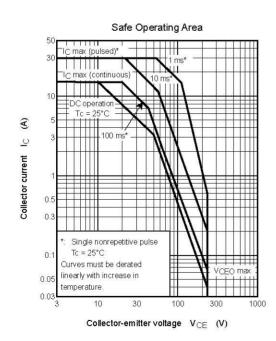
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Handbook" etc..

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#### TOSHIBA TRANSISTOR SILICON PNP TRIPLE DIFFUSED TYPE

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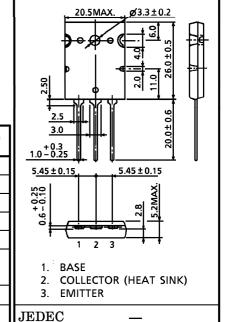
#### POWER AMPLIFIER APPLICATIONS

- Complementary to 2SC5200
- Recommended for 100 W High Fidelity Audio Frequency Amplifier Output Stage.

## MAXIMUM RATINGS (Tc = 25°C)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Collector-Base Voltage	$v_{\mathrm{CBO}}$	-230	V
Collector-Emitter Voltage	$v_{CEO}$	-230	V
Emitter-Base Voltage	$V_{ m EBO}$	-5	V
Collector Current	$I_{\mathbf{C}}$	-15	A
Base Current	$I_{\mathbf{B}}$	-1.5	A
Collector Power Dissipation (Tc = 25°C)	PC	150	W
Junction Temperature	Tj	150	°C
Storage Temperature Range	$\mathrm{T_{stg}}$	-55~150	°C

Unit in mm



TOSHIBA 2-21F1A Weight: 9.75 g (Typ.)

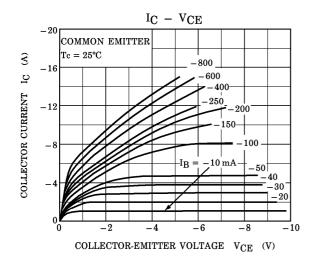
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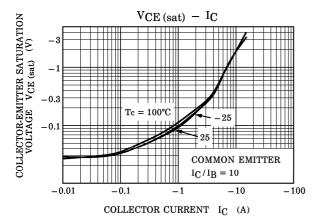
# ELECTRICAL CHARACTERISTICS (Tc = 25°C)

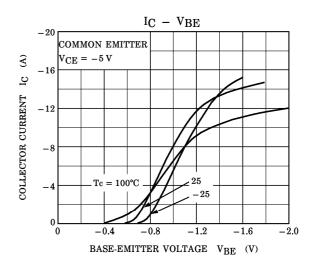
CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Collector Cut-off Current	$I_{CBO}$	$V_{CB} = -230 \text{ V}, I_{E} = 0$	_	_	-5.0	$\mu$ A
Emitter Cut-off Current	$I_{EBO}$	$V_{EB} = -5 \text{ V}, I_{C} = 0$	_	_	-5.0	$\mu$ A
Collector-Emitter Breakdown Voltage	V (BR) CEO	$I_{C} = -50 \text{ mA}, I_{B} = 0$	-230	_	_	V
DC Current Gain	h <sub>FE (1)</sub> (Note)	$V_{CE} = -5 \text{ V}, I_{C} = -1 \text{ A}$	55	_	160	
	h <sub>FE</sub> (2)	$V_{CE} = -5 \text{ V}, I_{C} = -7 \text{ A}$	35	60	_	
Collector-Emitter Saturation Voltage	V <sub>CE</sub> (sat)	$I_{\rm C} = -8{\rm A},\ I_{\rm B} = -0.8{\rm A}$	_	-1.5	-3.0	V
Base-Emitter Voltage	$v_{ m BE}$	$V_{CE} = -5 \text{ V}, I_{C} = -7 \text{ A}$	_	-1.0	-1.5	V
Transition Frequency	$ m f_{T}$	$V_{CE} = -5 \text{ V}, I_{C} = -1 \text{ A}$	_	30	_	MHz
Collector Output Capacitance	C <sub>ob</sub>	$V_{CB} = -10 V, I_{E} = 0,$ f = 1 MHz	_	360	_	pF

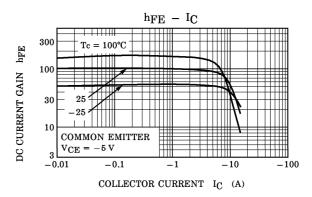
(Note):  $h_{FE(1)}$  Classification R: 55~110, O: 80~160

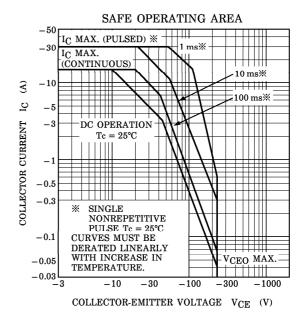
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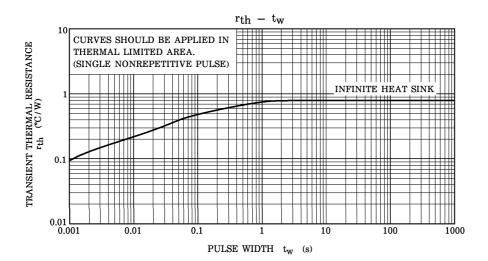








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